Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.230 inches and 0.300 inches

Terminal Length:

Between 1.000 inches and 1.500 inches

Overall Diameter:

Between 0.085 inches and 0.107 inches

Function For Which Designed:

Voltage variable capacitor

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, dc and 70.0 working peak reverse voltage

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector preset

Capacitance Rating In Picofarads:

33.0

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/383 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:
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No

Fiig:

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